

T..HFL SERIES

FAST RECOVERY DIODES

T-Modules

Features

- Fast recovery time characteristics
- Electrically isolated base plate
- 3500 V_{RMS} isolating voltage
- Standard JEDEC package
- Simplified mechanical designs,
rapid assembly
- Large creepage distances
- ULE78996 approved 

40 A
70 A
85 A

Description

This serie of T-module uses fast recovery power diodes in a single diode configuration. The semiconductors are electrically isolated from the metal base, allowing common heatsink and compact assemblies to be built.

These single diode modules can be used in conjunction with the thyristor modules as a freewheel diode. Application includes self-commutated inverters, DC choppers, motor control, inductive heating and electronic welders. These modules are intended for those applications where very fast recovery characteristics are required and for general power switching applications.

Major Ratings and Characteristics

Parameters	T40HFL	T70HFL	T85HFL	Units
I _{F(AV)}	40	70	85	A
I _{F(RMS)}	63	110	133	A
I _{FSM}	50Hz	475	830	A
	60Hz	500	870	A
I ² t	50Hz	1130	3460	A ² s
	60Hz	1030	3160	A ² s
V _{RRM} range	100 to 1000			V
t _{rr} range	200 to 1000			ns
T _J range	-40 to 125			°C

T..HFL Series

Bulletin I27107 rev. A 09/97

International
Rectifier

ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	t_{rr} Code	V_{RRM} , maximum repetitive peak reverse voltage V	V_{RSM} , maximum non-repetitive peak reverse voltage V	$I_{RRM}^{\text{max.}}$ $T_J = @25^\circ\text{C}$ μA
T40HFL..	10	S02, S05, S10	100	150	100
	20	S02, S05, S10	200	300	
	40	S02, S05, S10	400	500	
	60	S02, S05, S10	600	700	
	80	S05, S10	800	900	
	100	S05, S10	1000	1100	

Forward Conduction

Parameters	T40HFL	T70HFL	T85HFL	Units	Conditions
$I_{F(AV)}$ Max. average fwd current @ Case temperature	40	70	85	A	180° conduction, half sine wave
	70	70	70	°C	
$I_{F(RMS)}$ Max. RMS forward current	63	110	133	A	Sinusoidal half wave, Initial $T_J = T_{J,\text{max.}}$
I_{FSM} Max. peak, one-cycle forward, non-repetitive surge current	475	830	1300	A	
	500	870	1370		
	400	700	1100		
	420	730	1150		
I^2t Maximum I^2t for fusing	1130	3460	8550	A²s	t=10ms No voltage t=8.3ms reapplied t=10ms 100% V_{RRM} t=8.3ms reapplied
	1030	3160	7810		
	800	2450	6050		
	730	2230	5520		
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	11300	34600	85500	A²√s	t=0.1 to 10ms, no voltage reapplied
$V_{F(TO)1}$ Low level value of threshold voltage	0.82	0.87	0.84	V	$T_J = 25^\circ\text{C}, (16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$
$V_{F(TO)2}$ High level value of threshold voltage	0.84	0.90	0.86		$T_J = 25^\circ\text{C}, (I > \pi \times I_{F(AV)})$
r_{f1} Low level value of forward slope resistance	7.0	2.77	2.15	mΩ	$T_J = 25^\circ\text{C}, (16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$
r_{f2} High level value of forward slope resistance	6.8	2.67	2.07		$T_J = 25^\circ\text{C}, (I > \pi \times I_{F(AV)})$
V_{FM} Max. forward voltage drop	1.60	1.73	1.55	V	$I_{FM} = \pi \times I_{F(AV)}, T_J = 25^\circ\text{C}, tp = 400\mu\text{s square wave}$ $\text{Av. power} = V_{F(TO)} \times I_{F(AV)} + I_f \times (I_{F(RMS)})^2$

Blocking

Parameters	T40HFL	T70HFL	T85HFL	Units	Conditions
I_{RRM} Max. peak rev. leak. current	20			mA	$T_J = 125^\circ\text{C}$
V_{INS} RMS isolation voltage	3500			V	50Hz, circuit to base, all terminals shorted $T_J = 25^\circ\text{C}, t = 1\text{ s}$

Thermal and Mechanical Specifications

Parameters		T40HFL	T70HFL	T85HFL	Units	Conditions
T _J	Junction operating temp.	-40 to 125		°C		
T _{stg}	Storage temperature range	-40 to 150		°C		
R _{thJC}	Max. internal thermal resistance junction to case	0.85	0.53	0.46	K/W	Per module, DC operation
R _{thC-S}	Thermal resistance, case to heatsink	0.2		K/W	Mounting surface flat, smooth and greased. Per module	
T	Mounting Base to torque $\pm 10\%$ heatsink	1.3 $\pm 10\%$		Nm	M3.5 mounting screws (2) Non-lubricated threads	
	Busbar to Terminal	3 $\pm 10\%$		Nm	M5 screws terminals; non-lubricated threads	
wt	Approximate weight	54 (19)		g (oz)	See outline table	
	Case style	D-56			T-MODULE	

(2) A mounting compound is recommended and the torque should be rechecked after a period of about 3 hours to allow for the spread of the compound

ΔR Conduction

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

Devices	Sinusoidal conduction @ T _J max.					Rectangular conduction @ T _J max.					Units
	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	
T40HFL	0.06	0.08	0.10	0.14	0.24	0.05	0.08	0.10	0.15	0.24	K/W
T70HFL	0.05	0.06	0.08	0.11	0.19	0.04	0.06	0.08	0.12	0.19	
T85HFL	0.04	0.05	0.06	0.09	0.15	0.03	0.05	0.07	0.09	0.015	

Reverse Recovery Characteristics

Parameter	T40HFL			T70HFL			T85HFL			Units	Conditions (*)
	S02	S05	S10	S02	S05	S10	S02	S05	S10		
t _{rr} Maximum reverse recovery time	70	110	270	70	110	270	80	120	290	ns	T _J = 25 °C, -di _F /dt = 100A/μs I _F = 1 A to V _R = 30V
	200	500	1000	200	500	1000	200	500	1000	ns	T _J = 25 °C, -di _F /dt = 25A/μs I _{FM} = π x rated I _{F(AV)} , V _R = -30 V
Q _{rr} Maximum reverse recovered charge	0.25	0.4	1.35	0.25	0.4	1.35	0.3	0.6	1.6	μC	T _J = 25 °C, -di _F /dt = 100A/μs I _F = 1 A to V _R = 30V
	0.55	2.0	8.0	0.6	2.1	8.5	0.8	3.5	1.5	μC	T _J = 25 °C, -di _F /dt = 25A/μs I _{FM} = π x rated I _{F(AV)} , V _R = -30 V

(*) Tested on LEM 300A Diodemeter Tester

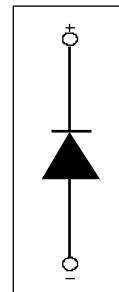
T..HFL Series

Bulletin I27107 rev. A 09/97

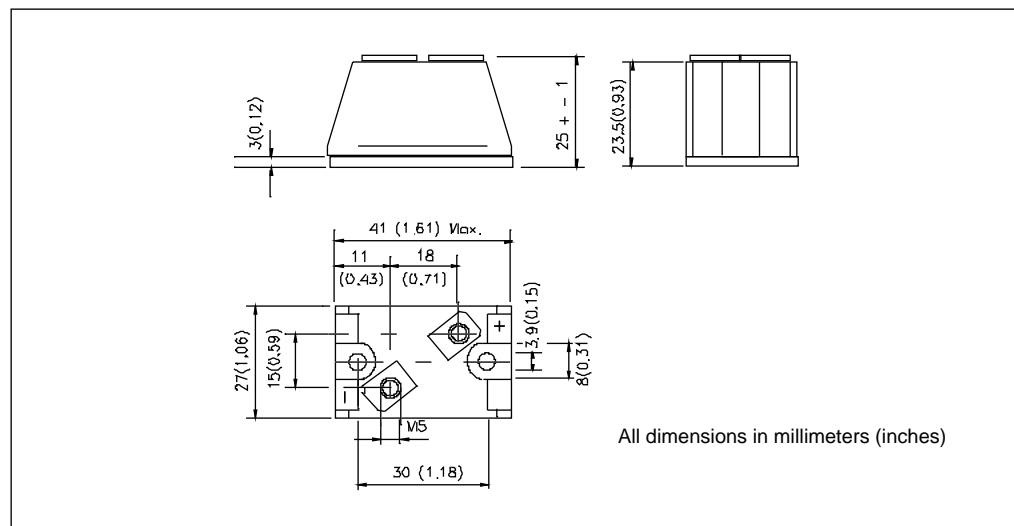
International
IR Rectifier

Ordering Information Table

Device Code				
1	T	40	HFL	100
2				S10
1	Module type			
2	Current rating:	40 = 40A (avg)		
		70 = 70A (avg)		
		85 = 85A (avg)		
3	-	Fast recovery diode		
4	-	Voltage code : code x 10 = V_{RRM}		
5	-	trr code:	S02 = 200ns	
			S05 = 500ns	
			S10 = 1000ns	



Outline Table



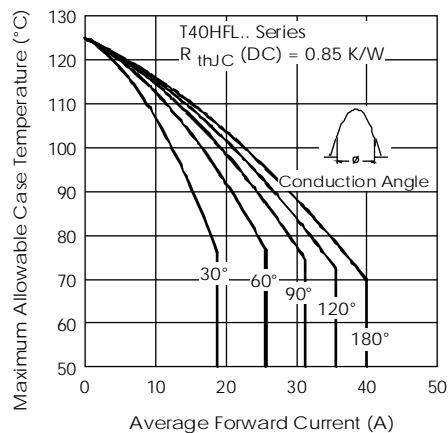


Fig. 1 - Current Ratings Characteristics

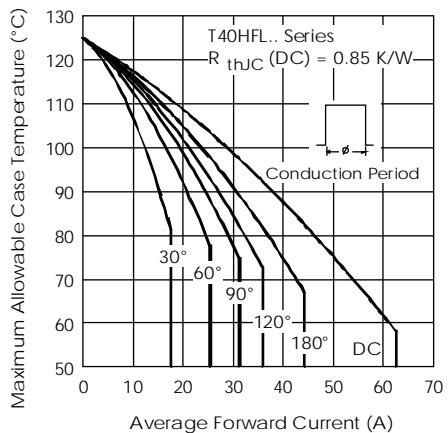


Fig. 2 - Current Ratings Characteristics

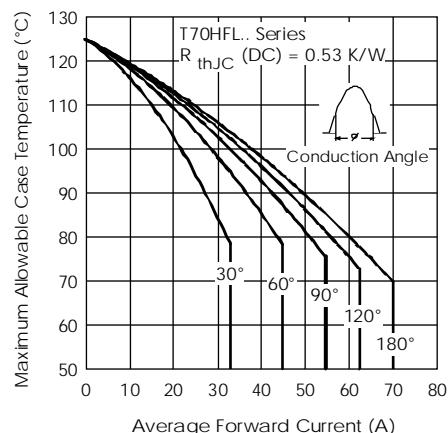


Fig. 3 - Current Ratings Characteristics

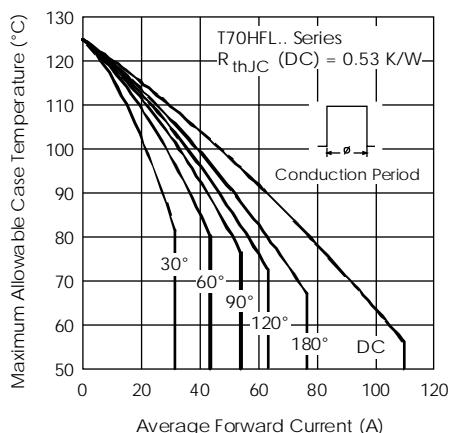


Fig. 4 - Current Ratings Characteristics

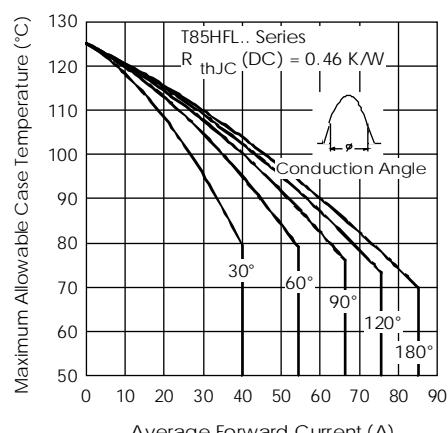


Fig. 5 - Current Ratings Characteristics

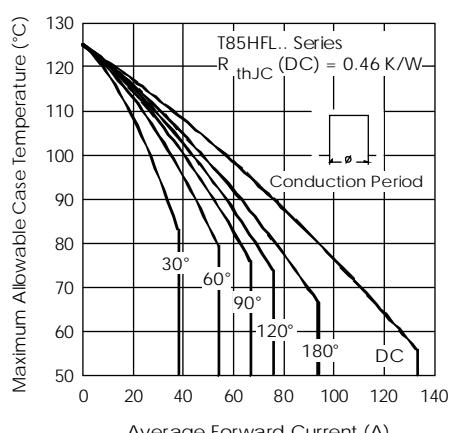


Fig. 6 - Current Ratings Characteristics

T..HFL Series

Bulletin I27107 rev. A 09/97

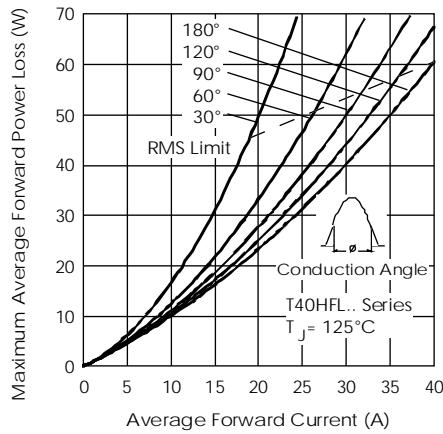


Fig. 7 - Forward Power Loss Characteristics

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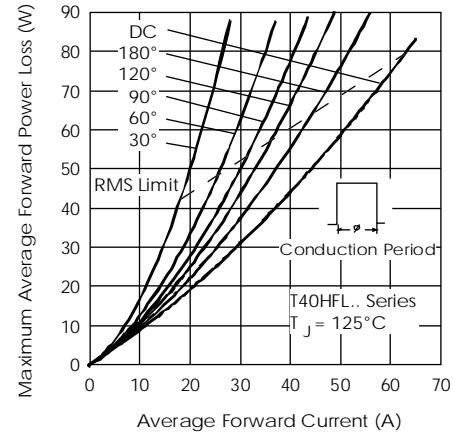


Fig. 8 - Forward Power Loss Characteristics

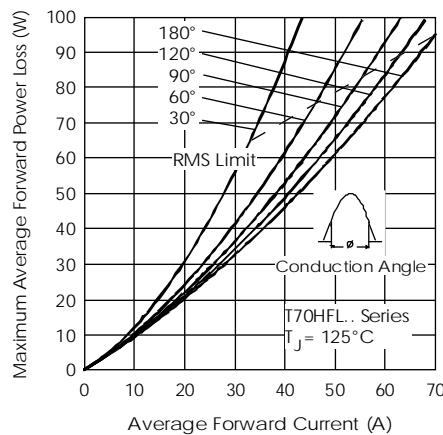


Fig. 9 - Forward Power Loss Characteristics

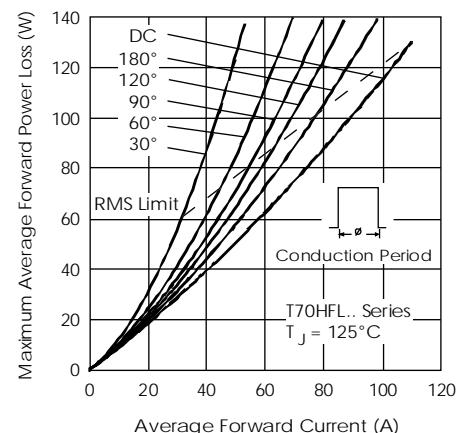


Fig. 10 - Forward Power Loss Characteristics

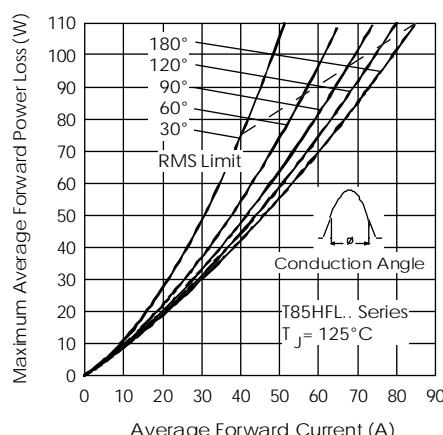


Fig. 11 - Forward Power Loss Characteristics

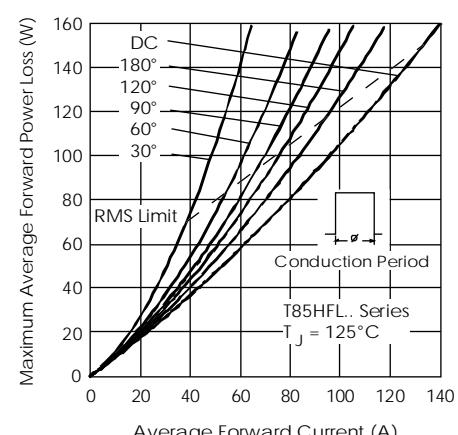


Fig. 12 - Forward Power Loss Characteristics

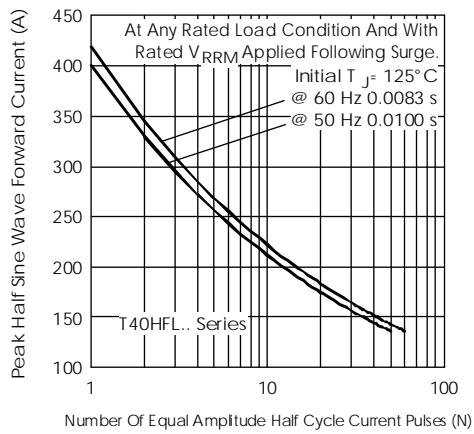


Fig. 13 - Maximum Non-Repetitive Surge Current

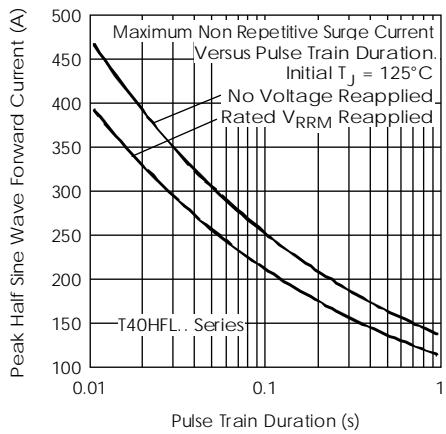


Fig. 14 - Maximum Non-Repetitive Surge Current

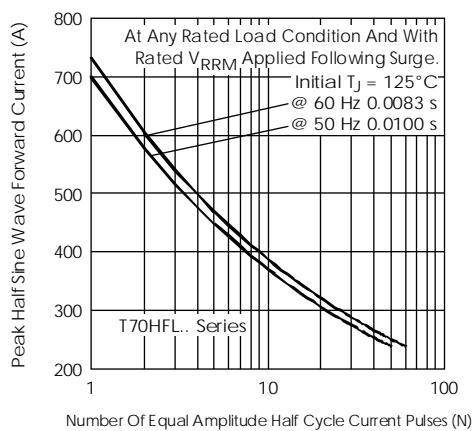


Fig. 15 - Maximum Non-Repetitive Surge Current

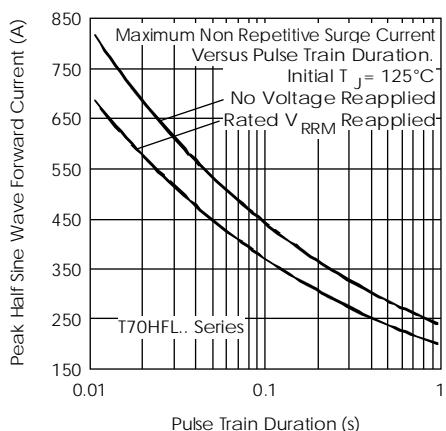


Fig. 16 - Maximum Non-Repetitive Surge Current

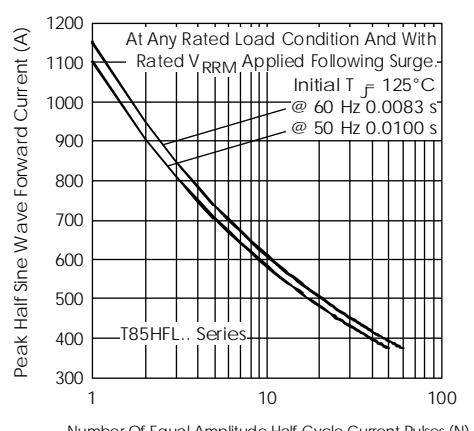


Fig. 17 - Maximum Non-Repetitive Surge Current

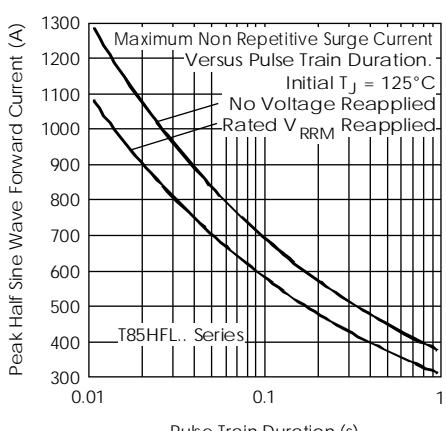


Fig. 18 - Maximum Non-Repetitive Surge Current

T..HFL Series

Bulletin I27107 rev. A 09/97

International
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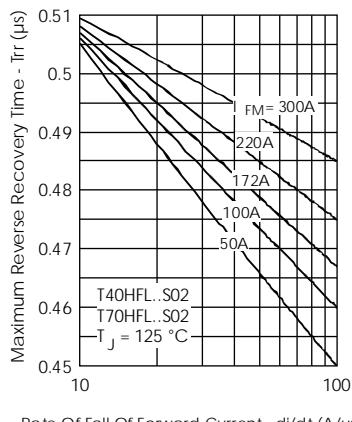


Fig. 19 - Recovery Time Characteristics

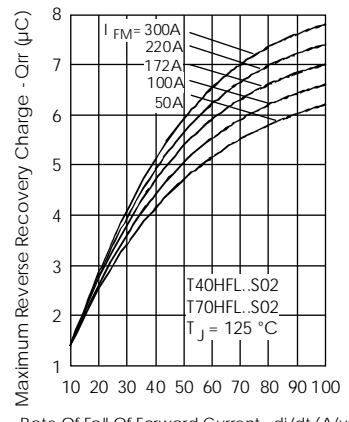


Fig. 20 - Recovery Charge Characteristics

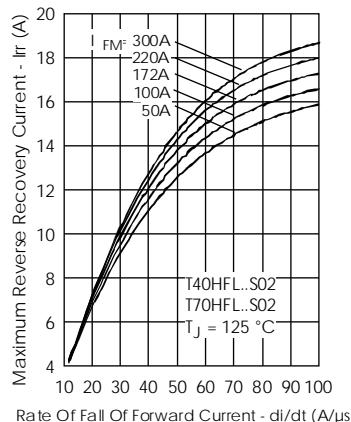


Fig. 21 - Recovery Current Characteristics

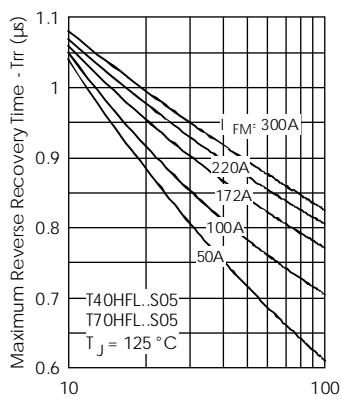


Fig. 22 - Recovery Time Characteristics

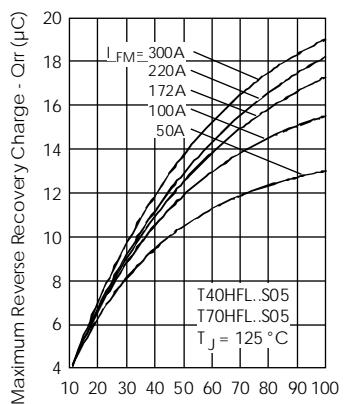


Fig. 23 - Recovery Charge Characteristics

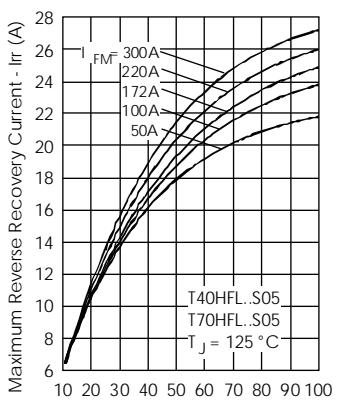


Fig. 24 - Recovery Current Characteristics

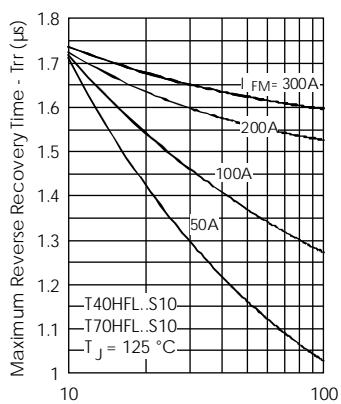


Fig. 25 - Recovery Time Characteristics

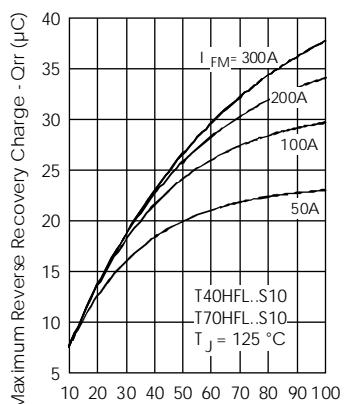


Fig. 26 - Recovery Charge Characteristics

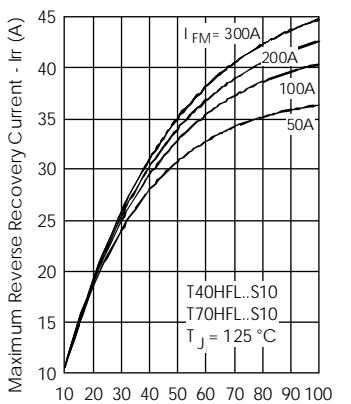


Fig. 27 - Recovery Current Characteristics

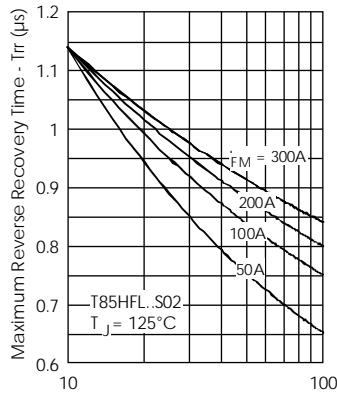


Fig. 28 - Recovery Time Characteristics

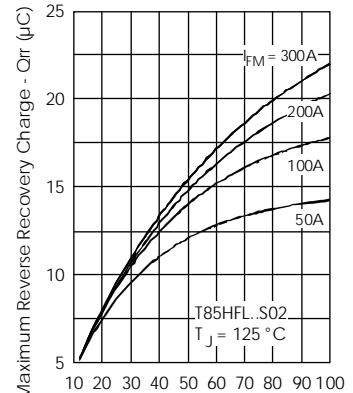


Fig. 29 - Recovery Charge Characteristics

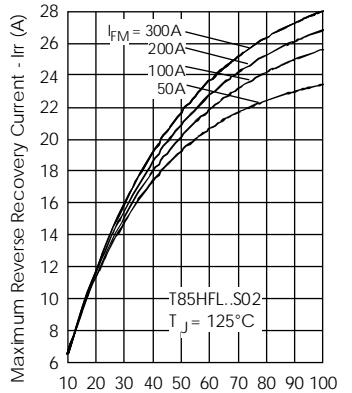


Fig. 30 - Recovery Current Characteristics

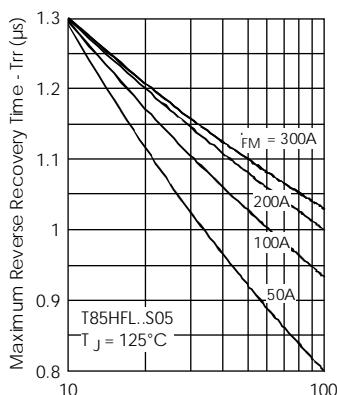


Fig. 31 - Recovery Time Characteristics

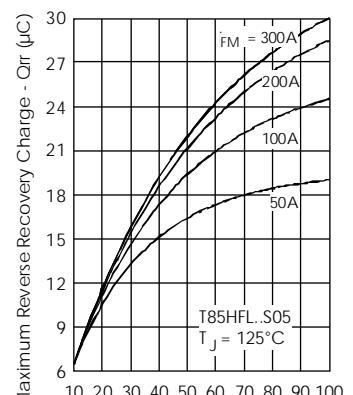


Fig. 32 - Recovery Charge Characteristics

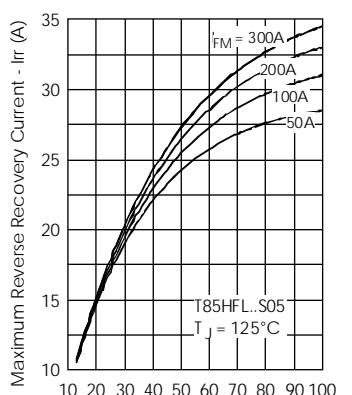


Fig. 33 - Recovery Current Characteristics

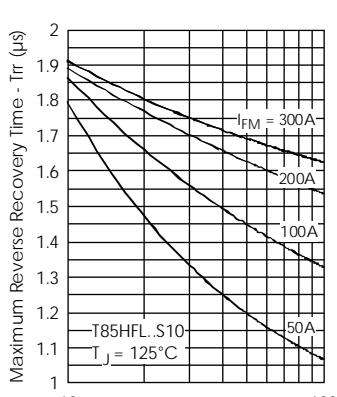


Fig. 34 - Recovery Time Characteristics

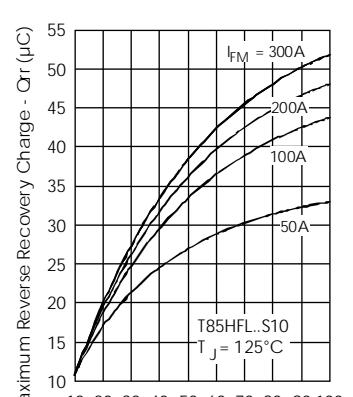


Fig. 35 - Recovery Charge Characteristics

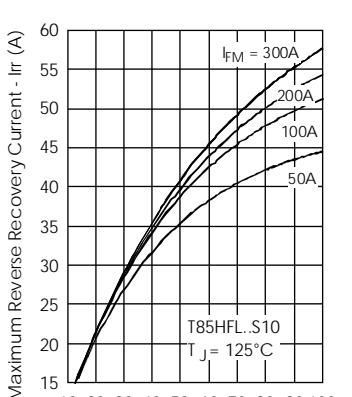


Fig. 36 - Recovery Current Characteristics

T..HFL Series

Bulletin I27107 rev. A 09/97

International
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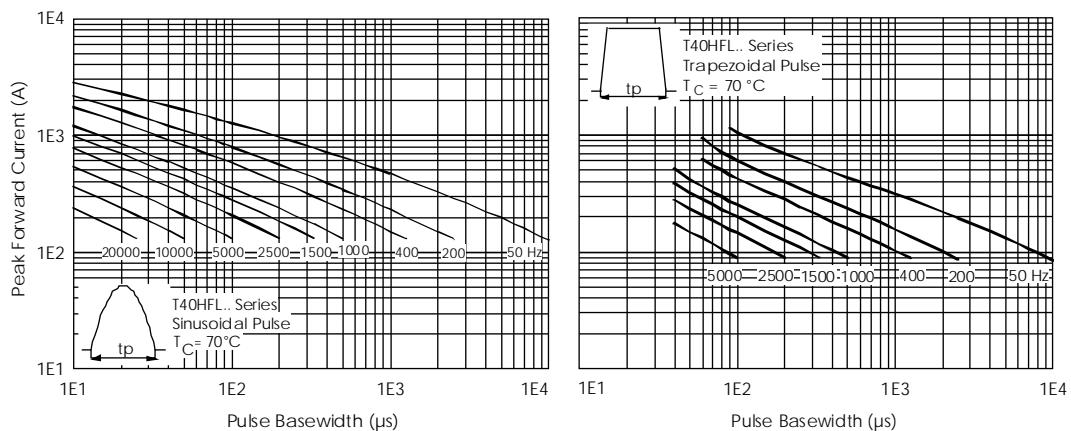


Fig. 37 - Frequency Characteristics

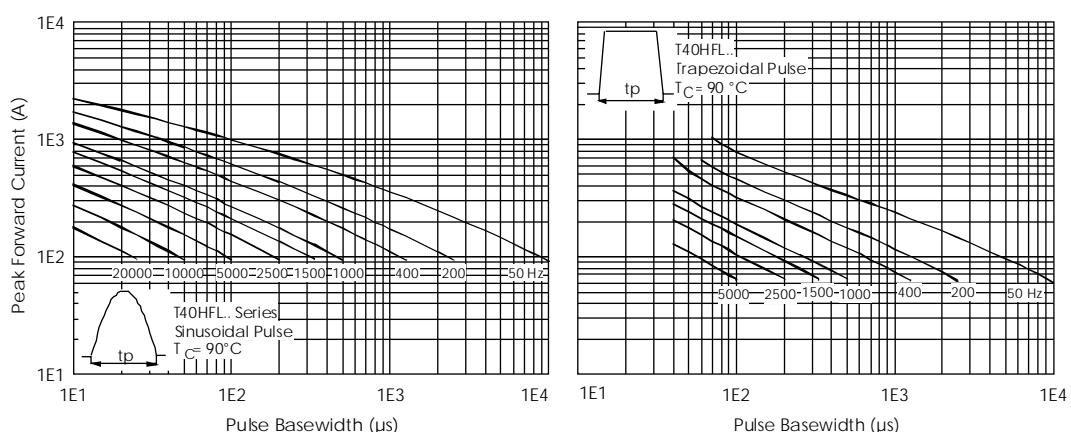


Fig. 38 - Frequency Characteristics

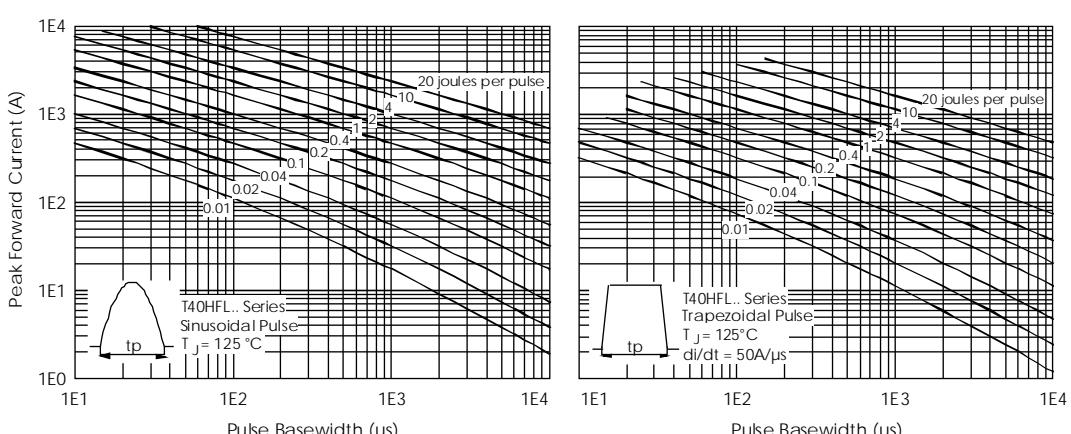
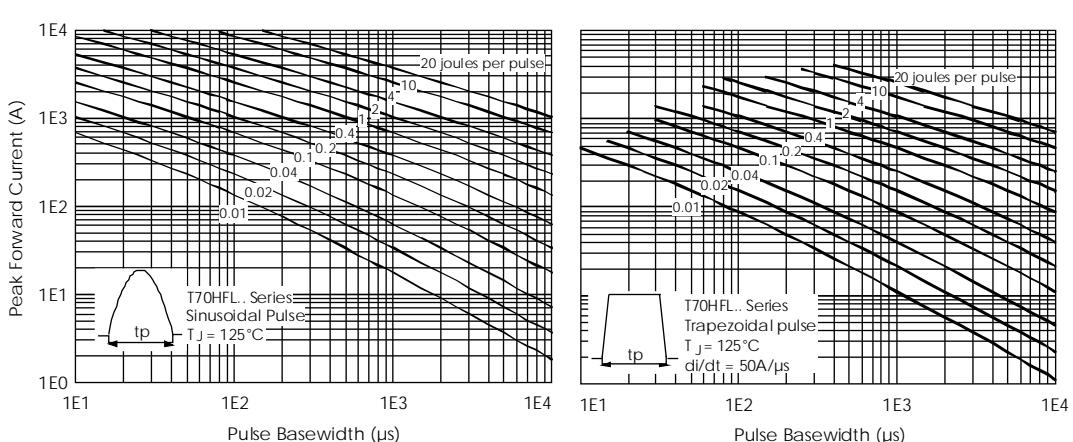
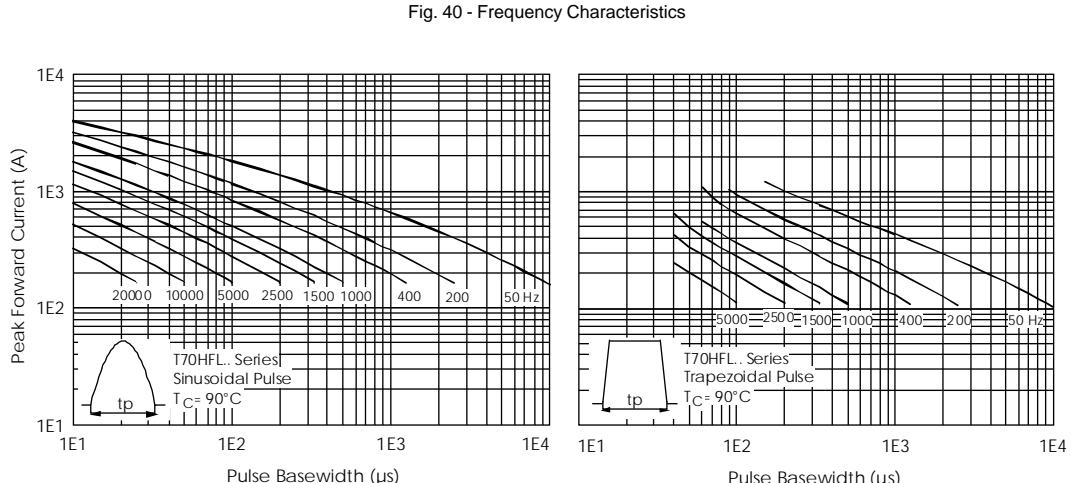
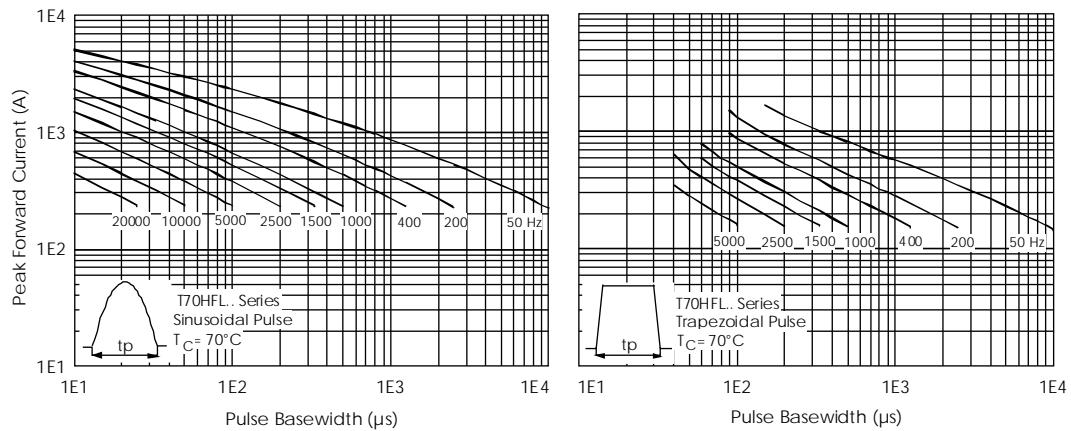


Fig. 39 - Maximum Forward Energy Power Loss Characteristics



T..HFL Series

Bulletin I27107 rev. A 09/97

International
IR Rectifier

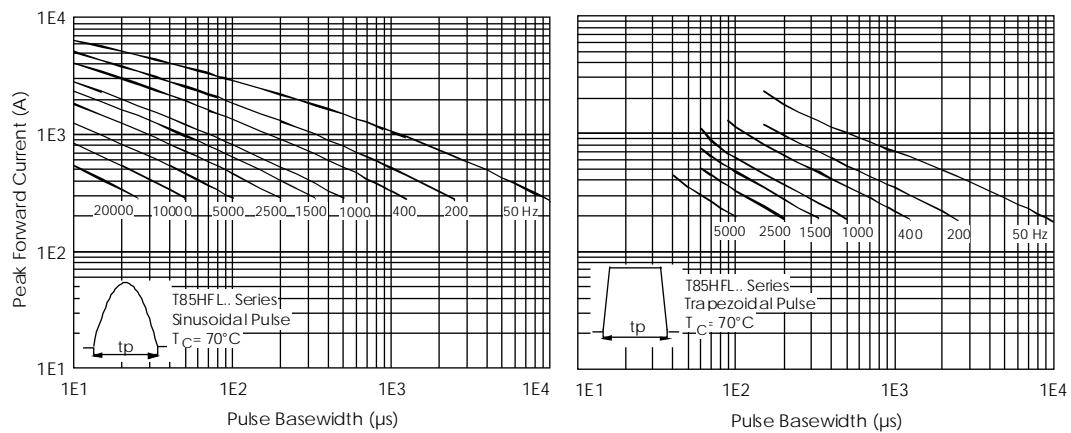


Fig. 43 - Frequency Characteristics

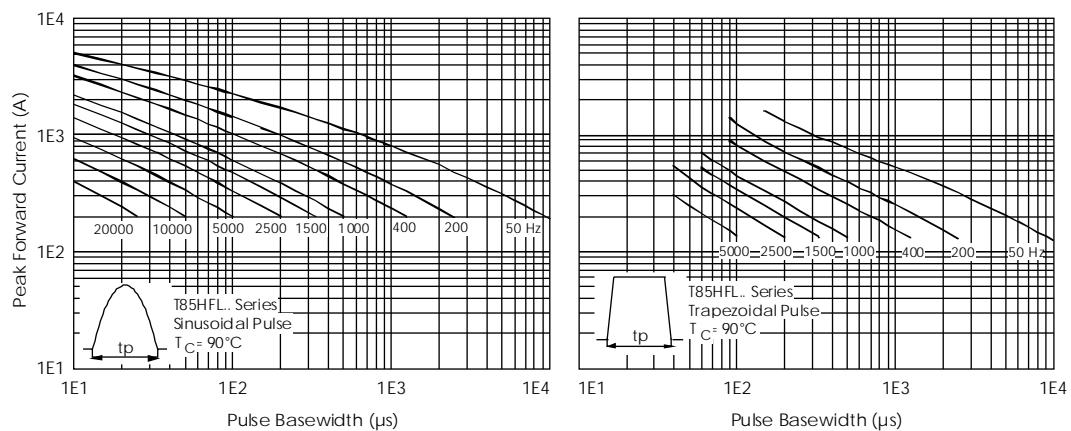


Fig. 44 - Frequency Characteristics

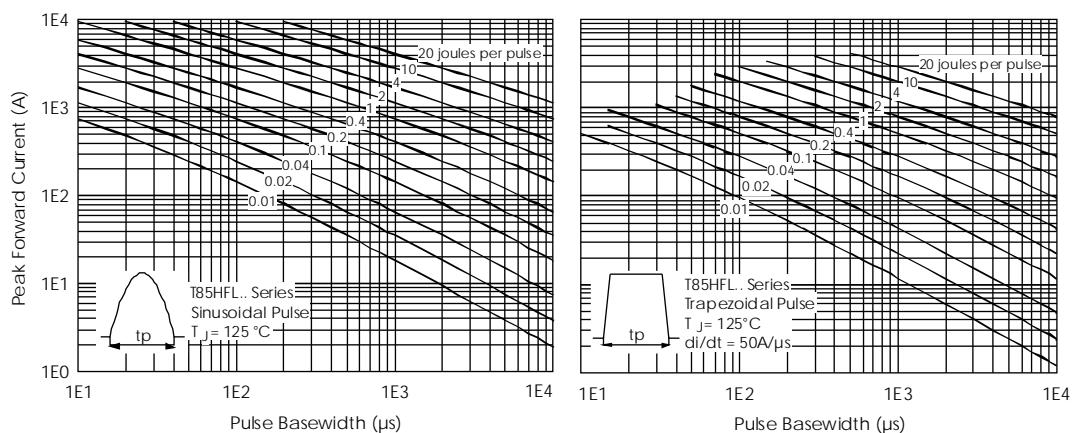


Fig. 45 - Maximum Forward Energy Power Loss Characteristics

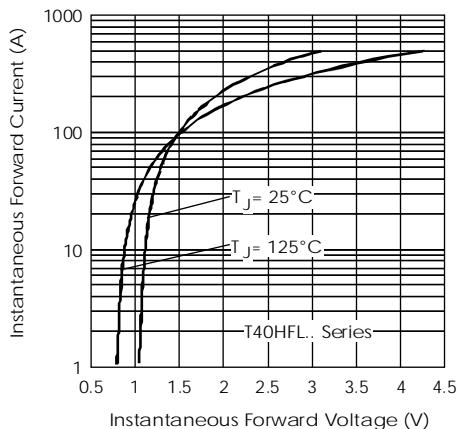


Fig. 46 - Forward Voltage Drop Characteristics

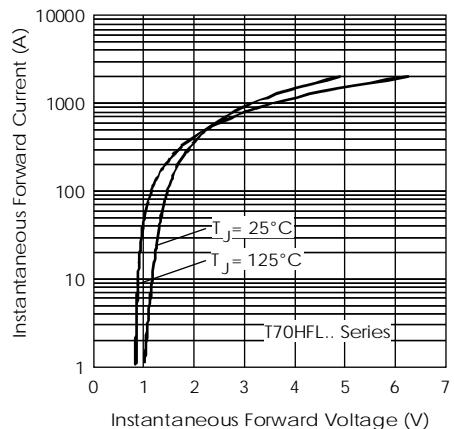


Fig. 47 - Forward Voltage Drop Characteristics

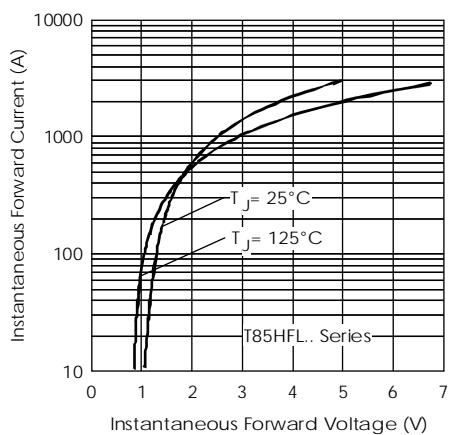


Fig. 48 - Forward Voltage Drop Characteristics

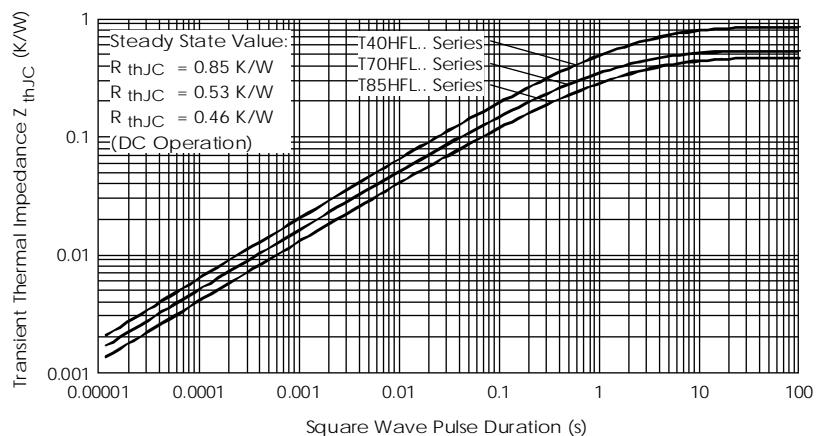


Fig. 49 - Thermal Impedance Z_{thJC} Characteristics